

PESDxL4UF; PESDxL4UG; PESDxL4UW

Low capacitance unidirectional quadruple ESD protection diode arrays

Rev. 04 — 28 February 2008

Product data sheet

1. Product profile

1.1 General description

Low capacitance unidirectional quadruple ElectroStatic Discharge (ESD) protection diode arrays in small Surface-Mounted Device (SMD) plastic packages designed to protect up to four signal lines from the damage caused by ESD and other transients.

Table 1. Product overview

Type number	Package			Package configuration
	NXP	JEITA	JEDEC	
PESD3V3L4UF	SOT886	-	MO-252	leadless ultra small
PESD5V0L4UF	SOT886	-	MO-252	leadless ultra small
PESD3V3L4UG	SOT353	SC-88A	-	very small
PESD5V0L4UG	SOT353	SC-88A	-	very small
PESD3V3L4UW	SOT665	-	-	ultra small and flat lead
PESD5V0L4UW	SOT665	-	-	ultra small and flat lead

1.2 Features

- ESD protection of up to four lines
- Low diode capacitance
- Max. peak pulse power: $P_{PP} = 30\text{ W}$
- Low clamping voltage: $V_{CL} = 12\text{ V}$
- Ultra low leakage current: $I_{RM} = 5\text{ nA}$
- ESD protection up to 20 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge); $I_{PP} = 2.5\text{ A}$

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Communication systems
- Portable electronics
- Subscriber Identity Module (SIM) card protection

1.4 Quick reference data

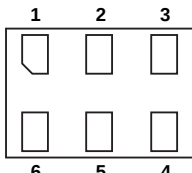
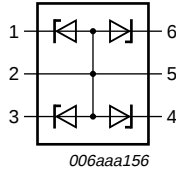
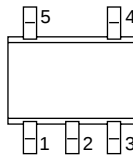
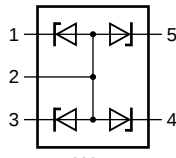
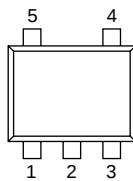
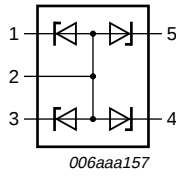
Table 2. Quick reference data

$T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per diode						
V_{RWM}	reverse standoff voltage					
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		-	-	3.3	V
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		-	-	5.0	V
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 0\text{ V}$				
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		-	22	28	pF
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		-	16	19	pF

2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
PESD3V3L4UF; PESD5V0L4UF			
1	cathode (diode 1)		
2	common anode		
3	cathode (diode 2)		
4	cathode (diode 3)		
5	common anode		
6	cathode (diode 4)		
bottom view			
PESD3V3L4UG; PESD5V0L4UG			
1	cathode (diode 1)		
2	common anode		
3	cathode (diode 2)		
4	cathode (diode 3)		
5	cathode (diode 4)		
PESD3V3L4UW; PESD5V0L4UW			
1	cathode (diode 1)		
2	common anode		
3	cathode (diode 2)		
4	cathode (diode 3)		
5	cathode (diode 4)		

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PESD3V3L4UF	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1.45 \times 0.5$ mm	SOT886
PESD5V0L4UF			
PESD3V3L4UG	SC-88A	plastic surface-mounted package; 5 leads	SOT353
PESD5V0L4UG			
PESD3V3L4UW	-	plastic surface-mounted package; 5 leads	SOT665
PESD5V0L4UW			

4. Marking

Table 5. Marking codes

Type number	Marking code ^[1]
PESD3V3L4UF	A5
PESD5V0L4UF	A6
PESD3V3L4UG	L1*
PESD5V0L4UG	L2*
PESD3V3L4UW	A2
PESD5V0L4UW	A1

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
P_{PP}	peak pulse power	$t_p = 8/20 \mu s$	[1] [2] [3]	30	W
I_{PP}	peak pulse current	$t_p = 8/20 \mu s$	[1] [2] [3]		
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		-	3.0	A
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		-	2.5	A
I_{FSM}	non-repetitive peak forward current	square wave; $t_p = 1$ ms	-	3.5	A

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
I_{ZSM}	non-repetitive peak reverse current	square wave; $t_p = 1\text{ ms}$			
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		-	0.9	A
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		-	0.8	A
P_{ZSM}	non-repetitive peak reverse power dissipation	square wave; $t_p = 1\text{ ms}$	-	6	W
Per device					
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-65	+150	°C
T_{stg}	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.

[2] For PESDxL4UF measured from pin 1, 3, 4 or 6 to pin 2 or 5.

[3] For PESDxL4UG and PESDxL4UW measured from pin 1, 3, 4 or 5 to pin 2.

Table 7. ESD maximum ratings $T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1][2][3] -	20	kV
		MIL-STD-883 (human body model)	-	10	kV

[1] Device stressed with ten non-repetitive ESD pulses.

[2] For PESDxL4UF measured from pin 1, 3, 4 or 6 to pin 2 or 5.

[3] For PESDxL4UG and PESDxL4UW measured from pin 1, 3, 4 or 5 to pin 2.

Table 8. ESD standards compliance

Standard	Conditions
Per diode	
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

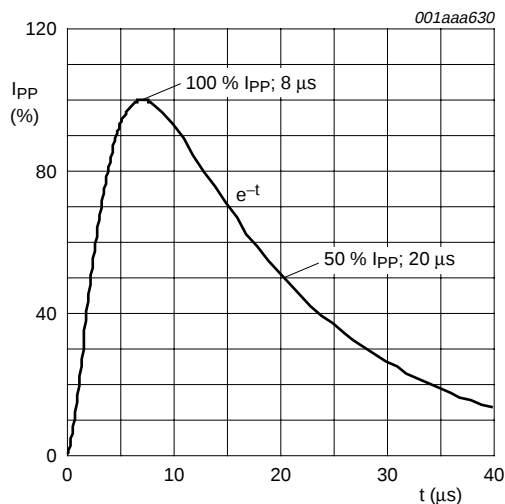


Fig 1. 8/20 μ s pulse waveform according to IEC 61000-4-5

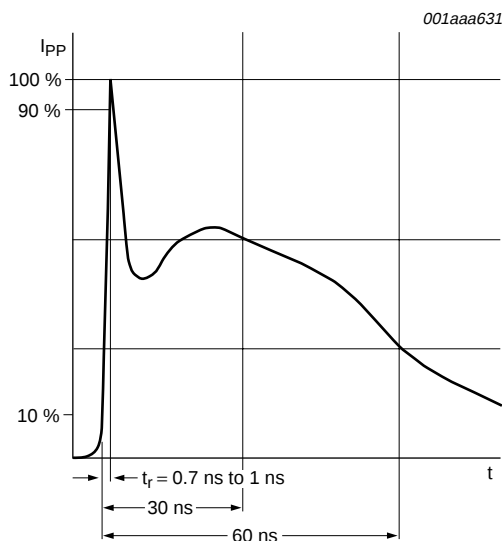


Fig 2. ESD pulse waveform according to IEC 61000-4-2

6. Characteristics

Table 9. Characteristics

$T_{amb} = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per diode						
V_{RWM}	reverse standoff voltage					
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		-	-	3.3	V
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		-	-	5.0	V
I_{RM}	reverse leakage current					
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW	$V_{RWM} = 3.3\text{ V}$	-	75	300	nA
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW	$V_{RWM} = 5.0\text{ V}$	-	5	25	nA
V_{BR}	breakdown voltage	$I_R = 1\text{ mA}$				
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		5.32	5.6	5.88	V
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		6.46	6.8	7.14	V

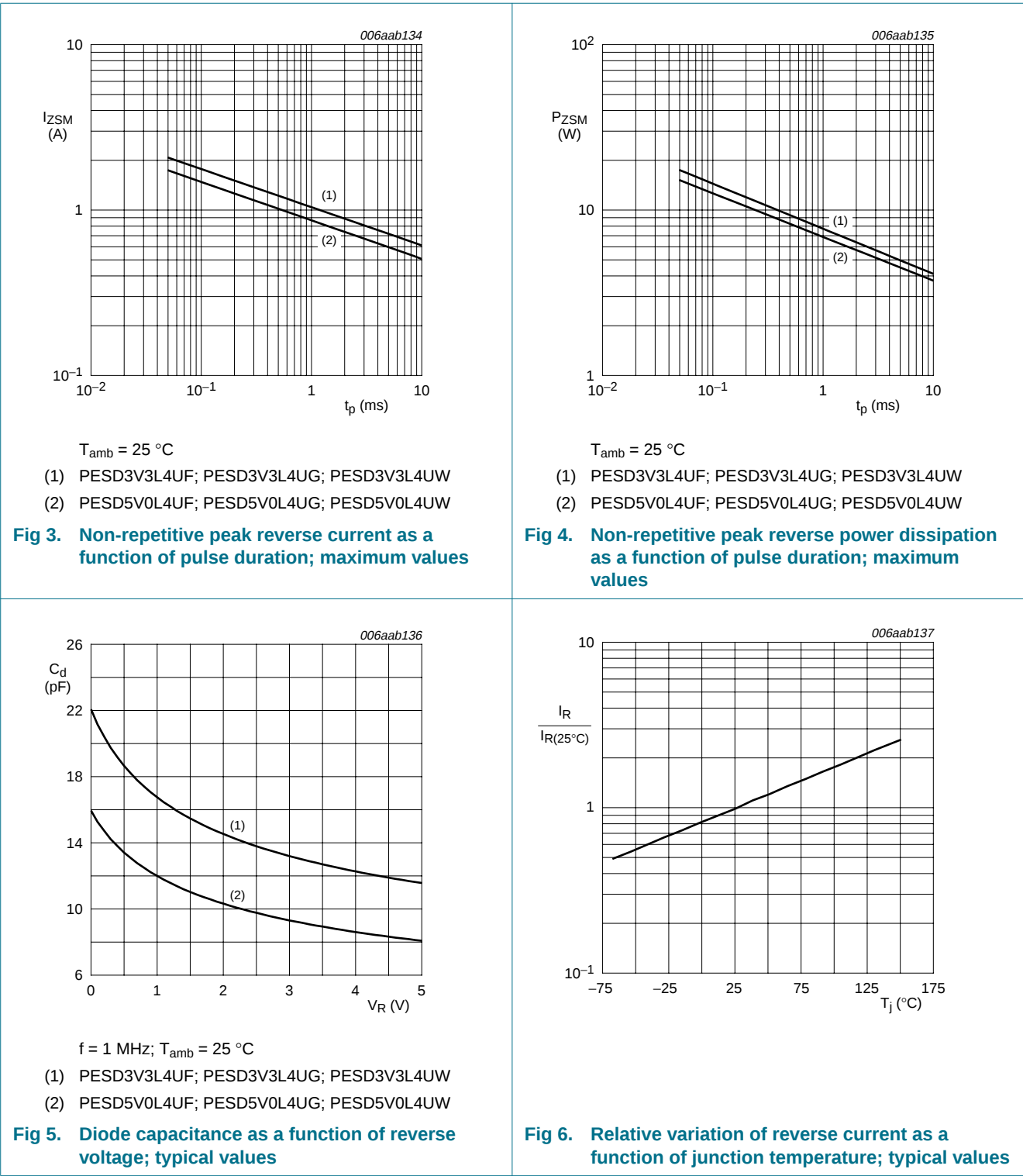
Table 9. Characteristics ...continued $T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified.

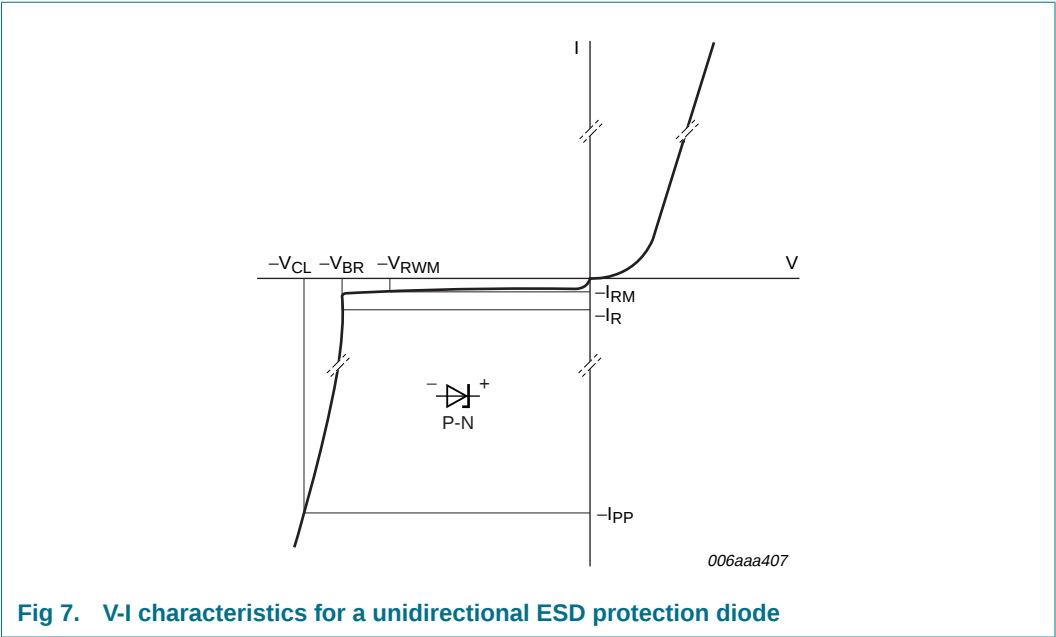
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C_d	diode capacitance	$f = 1\text{ MHz};$ $V_R = 0\text{ V}$				
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		-	22	28	pF
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		-	16	19	pF
	clamping voltage		[1] [2] [3]			
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW	$I_{PP} = 1\text{ A}$	-	-	8	V
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW	$I_{PP} = 3\text{ A}$	-	-	12	V
V_{CL}	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW	$I_{PP} = 1\text{ A}$	-	-	10	V
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW	$I_{PP} = 2.5\text{ A}$	-	-	13	V
	differential resistance	$I_R = 1\text{ mA}$				
	PESD3V3L4UF PESD3V3L4UG PESD3V3L4UW		-	-	200	Ω
	PESD5V0L4UF PESD5V0L4UG PESD5V0L4UW		-	-	100	Ω

[1] Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.

[2] For PESDxL4UF measured from pin 1, 3, 4 or 6 to pin 2 or 5.

[3] For PESDxL4UG and PESDxL4UW measured from pin 1, 3, 4 or 5 to pin 2.





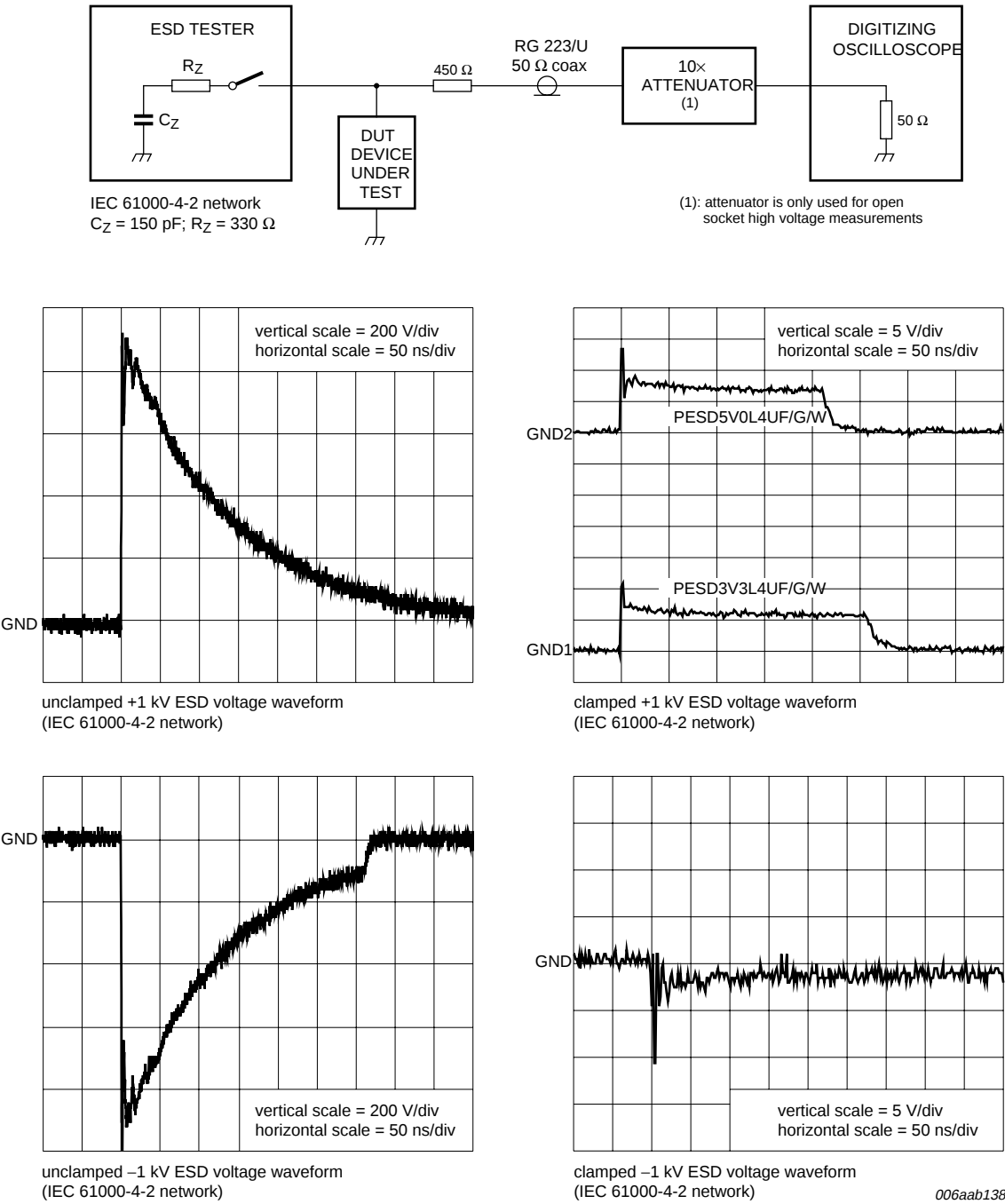
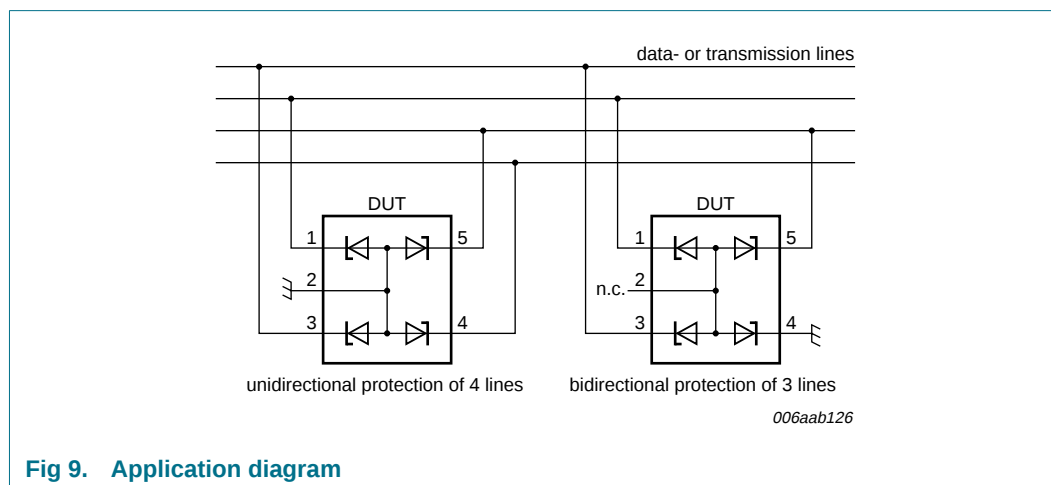


Fig 8. ESD clamping test setup and waveforms

7. Application information

The devices are designed for the protection of up to four unidirectional data or signal lines from the damage caused by ESD and surge pulses. The devices may be used on lines where the signal polarities are both, positive and negative with respect to ground. The devices provide a surge capability of 30 W per line for an 8/20 μ s waveform each.

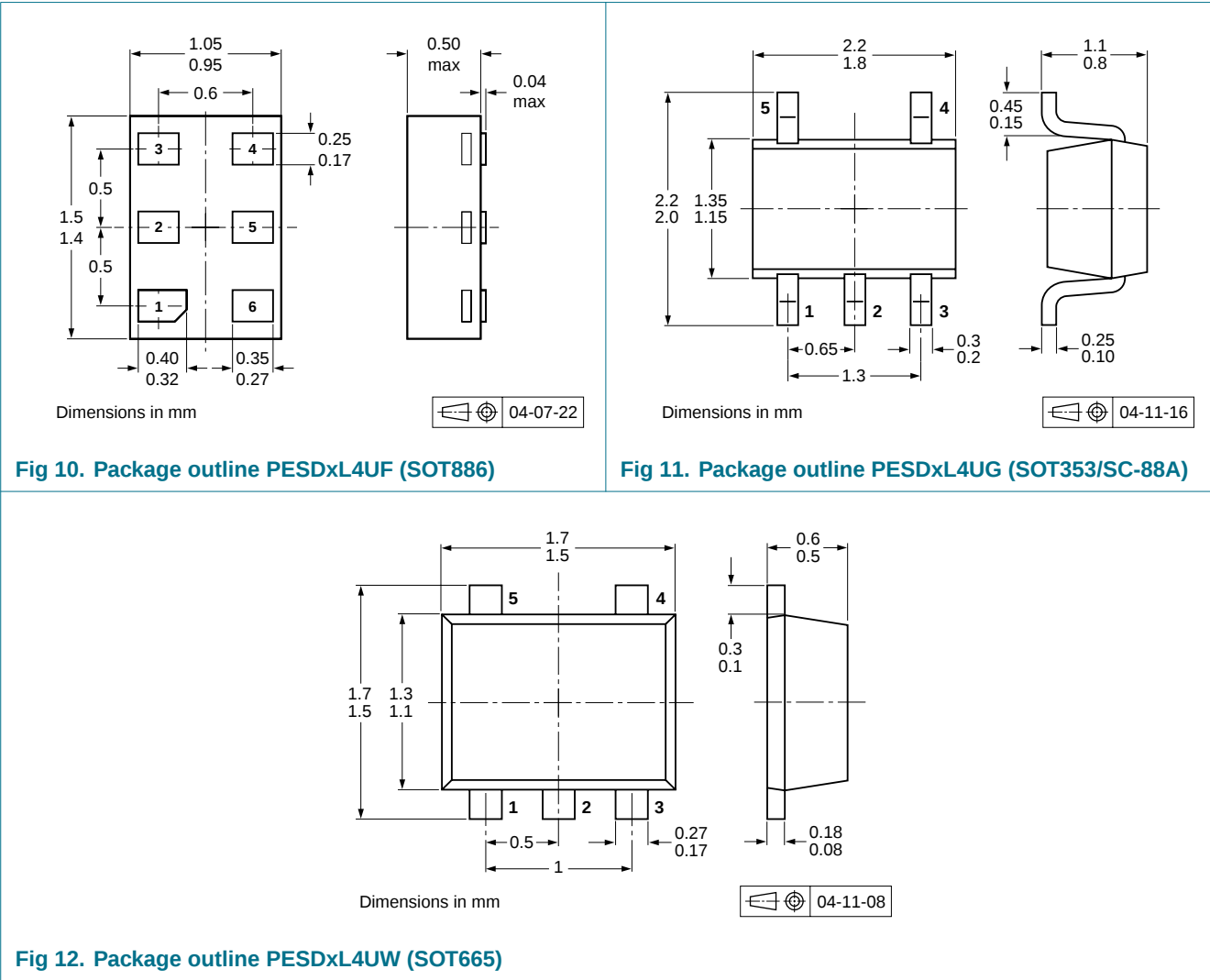


Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

1. Place the device as close to the input terminal or connector as possible.
2. The path length between the device and the protected line should be minimized.
3. Keep parallel signal paths to a minimum.
4. Avoid running protected conductors in parallel with unprotected conductors.
5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

8. Package outline



9. Packing information

Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

Type number	Package	Description	Packing quantity				
			3000	4000	5000	8000	10000
PESD3V3L4UF	SOT886	4 mm pitch, 8 mm tape and reel; T1	[2]	-	-	-115	-
		4 mm pitch, 8 mm tape and reel; T4	[3]	-	-	-132	-
PESD5V0L4UF	SOT886	4 mm pitch, 8 mm tape and reel; T1	[2]	-	-	-115	-
		4 mm pitch, 8 mm tape and reel; T4	[3]	-	-	-132	-
PESD3V3L4UG	SOT353	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	[4]	-125	-	-	-165
PESD5V0L4UG	SOT353	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	[4]	-125	-	-	-165
PESD3V3L4UW	SOT665	2 mm pitch, 8 mm tape and reel	-	-	-	-315	-
		4 mm pitch, 8 mm tape and reel	-	-115	-	-	-
PESD5V0L4UW	SOT665	2 mm pitch, 8 mm tape and reel	-	-	-	-315	-
		4 mm pitch, 8 mm tape and reel	-	-115	-	-	-

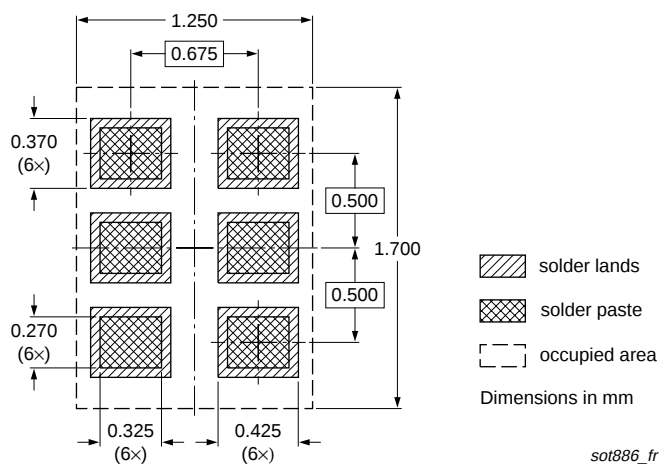
[1] For further information and the availability of packing methods, see [Section 13](#).

[2] T1: normal taping

[3] T4: 90° rotated reverse taping

[4] T2: reverse taping

10. Soldering



Reflow soldering is the only recommended soldering method.

Fig 13. Reflow soldering footprint PESDxL4UF (SOT886)

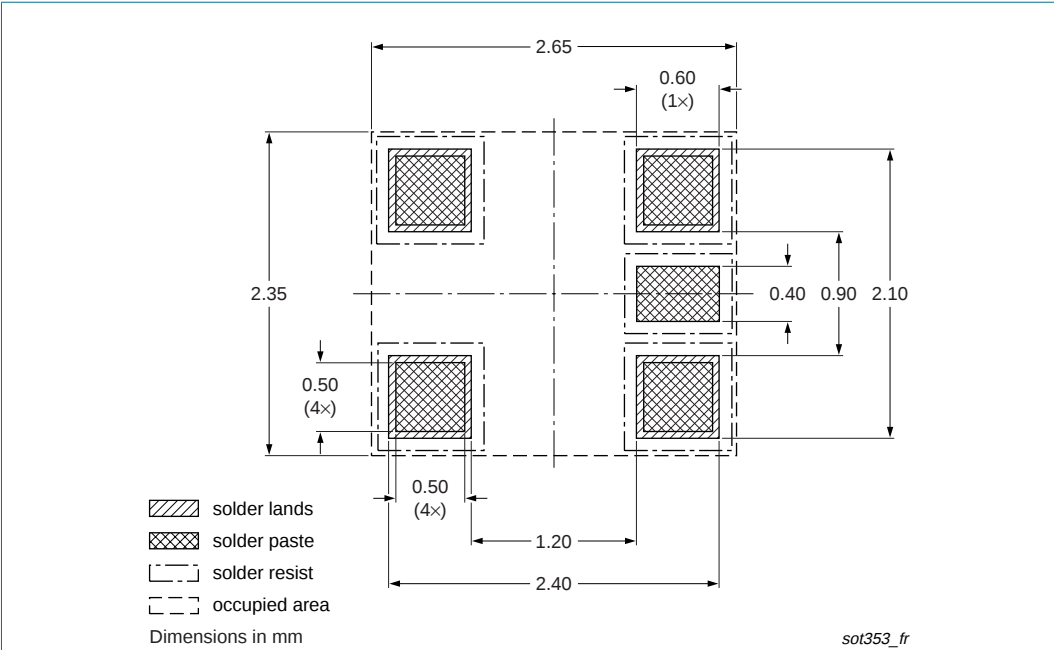


Fig 14. Reflow soldering footprint PESDxL4UG (SOT353/SC-88A)

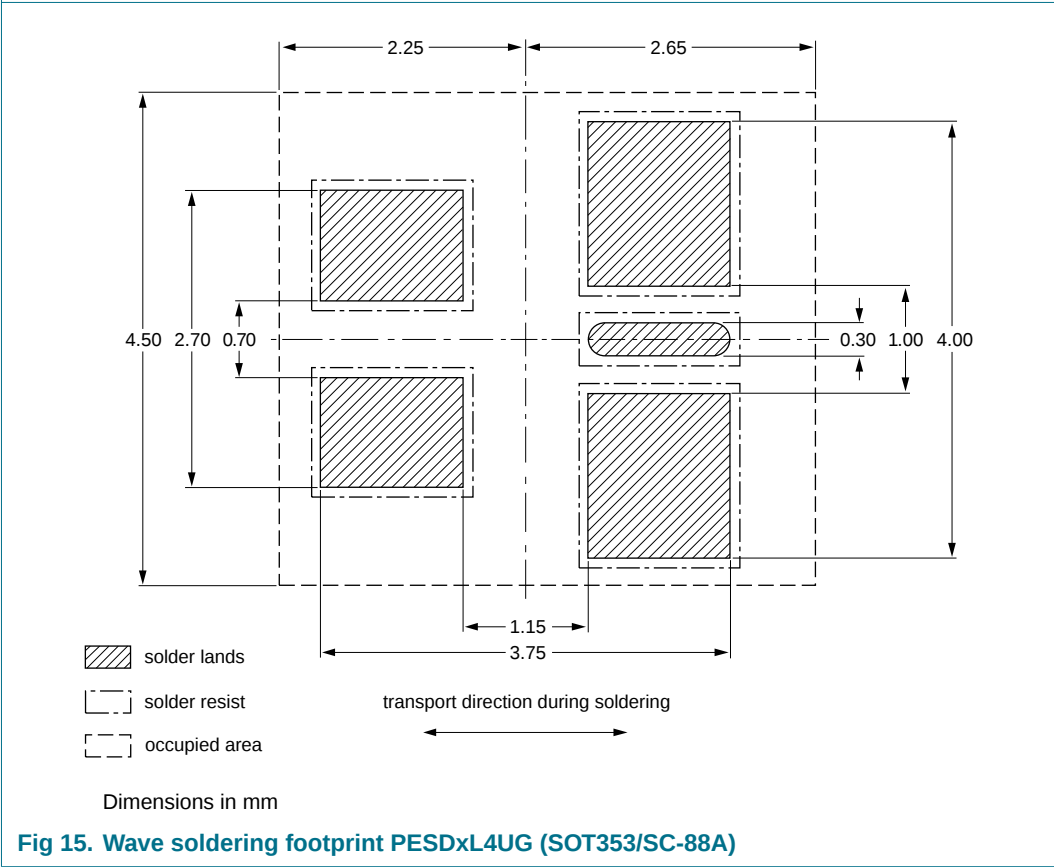
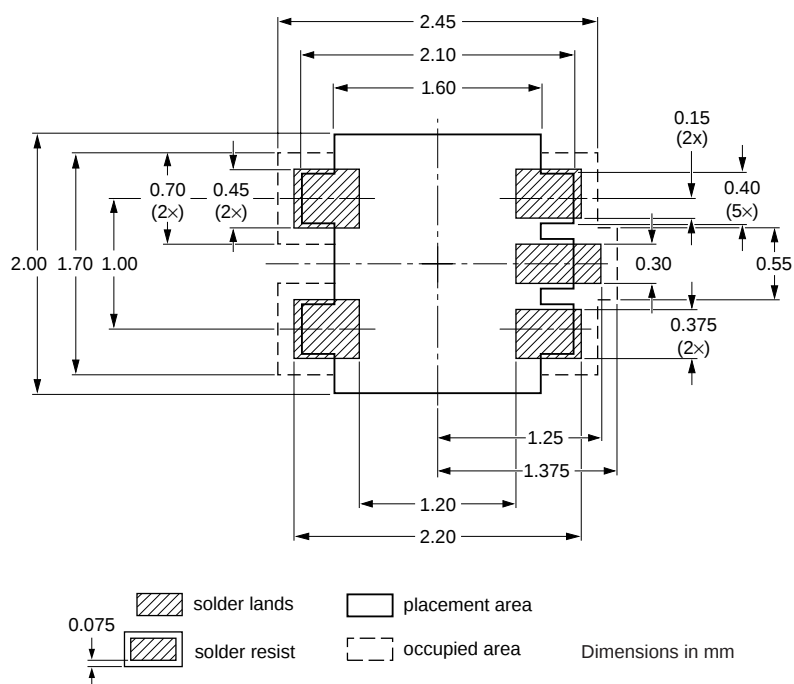


Fig 15. Wave soldering footprint PESDxL4UG (SOT353/SC-88A)



Reflow soldering is the only recommended soldering method.

Fig 16. Reflow soldering footprint PESDxL4UW (SOT665)

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESDXL4UF_G_W_4	20080228	Product data sheet	-	PESDXL4UF_G_W_3
Modifications:	• Figure 8 “ESD clamping test setup and waveforms” : amended			
PESDXL4UF_G_W_3	20080114	Product data sheet	-	PESDXL4UW_SER_2 PESDXL4UG_SERIES_1
PESDXL4UW_SER_2	20040406	Product specification	-	PESDXL4UW_SERIES_1
PESDXL4UG_SERIES_1	20040323	Product specification	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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